TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74ACT273P,TC74ACT273F,TC74ACT273FW

Octal D-Type Flip Flop with Clear

The TC74ACT273 is an advanced high speed CMOS OCTAL D-TYPE FLIP FLOP fabricated with silicon gate and double-layer metal wiring C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

This device may be used as a level converter for interfacing TTL or NMOS to High Speed CMOS. The inputs are compatible with TTL, NMOS and CMOS output voltage levels.

Information signals applied to D inputs are transferred to the Q outputs on the positive going edge of the clock pulse.

When the $\overline{\text{CLR}}$ input is held "L", the Q outputs are at a low logic level independent of the other inputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

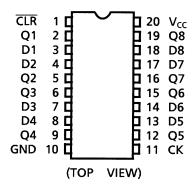
Features

- High speed: $f_{max} = 170 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: ICC = 8 μA (max) at Ta = 25°C
- Compatible with TTL outputs: $V_{IL} = 0.8 \text{ V (max)}$

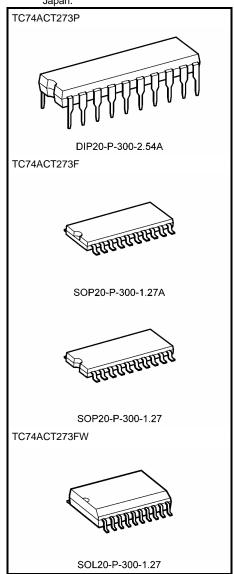
$$VIH = 2.0 V (min)$$

- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 24$ mA (min) Capability of driving 50 Ω transmission lines.
- Balanced propagation delays: $t_pLH \simeq t_pHL$
- Pin and function compatible with 74F273

Pin Assignment



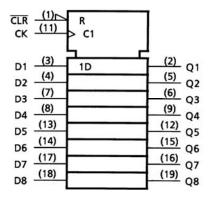
Note: xxxFW (JEDEC SOP) is not available in Japan.



Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.) SOP20-P-300-1.27 : 0.22 g (typ.) SOL20-P-300-1.27 : 0.46 g (typ.)

IEC Logic Symbol

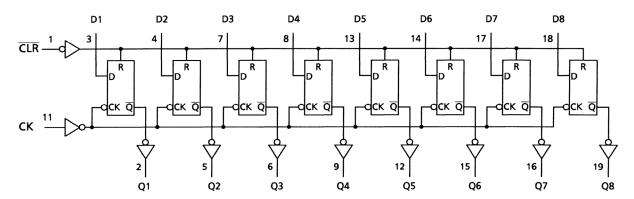


Truth Table

| | Inputs | | Output | Function |
|-----|--------|--------|----------------|------------|
| CLR | D | CK | Q | 1 diletion |
| L | Х | Х | L | Clear |
| Н | L | | L | _ |
| Н | Н | | Н | _ |
| Н | Х | \Box | Q _n | No Change |

X: Don't care

System Diagram





Absolute Maximum Ratings (Note 1)

| Characteristics | Symbol | Rating | Unit |
|------------------------------------|------------------|-------------------------------|------|
| Supply voltage range | Vcc | -0.5 to 7.0 | V |
| DC input voltage | V _{IN} | -0.5 to V _{CC} + 0.5 | V |
| DC output voltage | V _{OUT} | −0.5 to V _{CC} + 0.5 | ٧ |
| Input diode current | I _{IK} | ±20 | mA |
| Output diode current | lok | ±50 | mA |
| DC output current | l _{OUT} | ±50 | mA |
| DC V _{CC} /ground current | Icc | ±200 | mA |
| Power dissipation | P _D | 500 (DIP) (Note 2)/180 (SOP) | mW |
| Storage temperature | T _{stg} | -65 to 150 | °C |

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of Ta = -40 to 65°C. From Ta = 65 to 85°C a derating factor of -10 mW/°C should be applied up to 300 mW.

Recommended Operating Conditions (Note)

| Characteristics | Symbol | Rating | Unit |
|--------------------------|------------------|----------------------|------|
| Supply voltage | V _{CC} | 4.5 to 5.5 | V |
| Input voltage | V_{IN} | 0 to V _{CC} | > |
| Output voltage | V _{OUT} | 0 to V _{CC} | V |
| Operating temperature | T _{opr} | -40 to 85 | °C |
| Input rise and fall time | dt/dV | 0 to 10 | ns/V |

Note: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.



Electrical Characteristics

DC Characteristics

| Characteristics | Symbol | Test Condition | | | Ta = 25°C | | | Ta = -40 to 85°C | | Unit | |
|---------------------------|-----------------|---------------------------------------------------------------------|------------------------------------------|---------------------|---------------|------|-----|---------------------|------|------|----|
| Onaracteristics | Cymbol | | | V _{CC} (V) | Min | Тур. | Max | Min | Max | Onne | |
| High-level input voltage | V _{IH} | _ | | | 4.5 to 5.5 | 2.0 | _ | _ | 2.0 | _ | V |
| Low-level input voltage | V_{IL} | _ | | | 4.5 to 5.5 | | _ | 0.8 | | 0.8 | V |
| | Voн | V _{IN} = V _{IH} or V _{IL} | $I_{OH} = -50 \ \mu A$ | | 4.5 | 4.4 | 4.5 | _ | 4.4 | _ | |
| High-level output voltage | | | $I_{OH} = -24 \text{ mA}$ | | 4.5 | 3.94 | _ | _ | 3.80 | _ | ٧ |
| | | | $I_{OH} = -75 \text{ mA}$ | (Note) | 5.5 | _ | _ | _ | 3.85 | _ | |
| | V _{OL} | V _{IN} = V _{IH} or V _{IL} | $I_{OL} = 50 \mu A$ | | 4.5 | _ | 0.0 | 0.1 | _ | 0.1 | |
| Low-level output voltage | | | $I_{OL} = 24 \text{ mA}$ | | 4.5 | _ | _ | 0.36 | _ | 0.44 | V |
| | | | $I_{OL} = 75 \text{ mA}$ | (Note) | 5.5 | _ | _ | _ | _ | 1.65 | |
| Input leakage current | I _{IN} | $V_{IN} = V_{CC}$ or GND | | | 5.5 | _ | _ | ±0.1 | _ | ±1.0 | μА |
| Quiescent supply current | I _{CC} | $V_{IN} = V_{C}$ | V _{IN} = V _{CC} or GND | | | _ | _ | 8.0 | _ | 80.0 | μΑ |
| | I _C | Per input: $V_{IN} = 3.4 \text{ V}$ Other input: V_{CC} or GND | | | 5.5 | _ | _ | 1.35 | _ | 1.5 | mA |

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

Timing Requirements (input: $t_r = t_f = 3 \text{ ns}$)

| Characteristics | Symbol | Test Condition | | | Ta = -40 to 85°C | Unit |
|--------------------------------------------------|--------------------|----------------|---------------------|-------|------------------------|------|
| | | | V _{CC} (V) | Limit | Limit | |
| Minimum pulse width (CK) | t _{W (L)} | _ | 5.0 ± 0.5 | 5.0 | 5.0 | ns |
| Minimum pulse width (CLR) | t _{W (L)} | _ | 5.0 ± 0.5 | 5.0 | 5.0 | ns |
| Minimum set-up time | ts | _ | 5.0 ± 0.5 | 3.5 | 3.5 | ns |
| Minimum hold time | t _h | _ | 5.0 ± 0.5 | 1.5 | 1.5 | ns |
| Minimum removal time ($\overline{\text{CLR}}$) | t _{rem} | _ | 5.0 ± 0.5 | 3.0 | 3.0 | ns |



AC Characteristics (C $_L$ = 50 pF, R_L = 500 $\Omega,$ input: t_r = t_f = 3 ns)

| Characteristics | Symbol | Test Condition | | Ta = 25°C | | | Ta = -40 to 85°C | | Unit |
|----------------------------------|--------------------------------------|----------------|---------------------|-----------|------|------|---------------------|------|------|
| | , | | V _{CC} (V) | Min | Тур. | Max | Min | Max | |
| Propagation delay time (CK-Q) | t _{pLH} t _{pHL} | _ | 5.0 ± 0.5 | _ | 6.6 | 10.5 | 1.0 | 12.0 | ns |
| Propagation delay time (CLR -Q) | t _{pHL} | _ | 5.0 ± 0.5 | _ | 7.4 | 10.8 | 1.0 | 12.3 | ns |
| Maximum clock frequency | f _{max} | 1 | 5.0 ± 0.5 | 80 | 150 | | 80 | | MHz |
| Input capacitance | C _{IN} | _ | | _ | 5 | 10 | _ | 10 | pF |
| Power dissipation capacitance | C _{PD} (Note) | | | _ | 34 | _ | _ | _ | pF |

Note: CPD is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

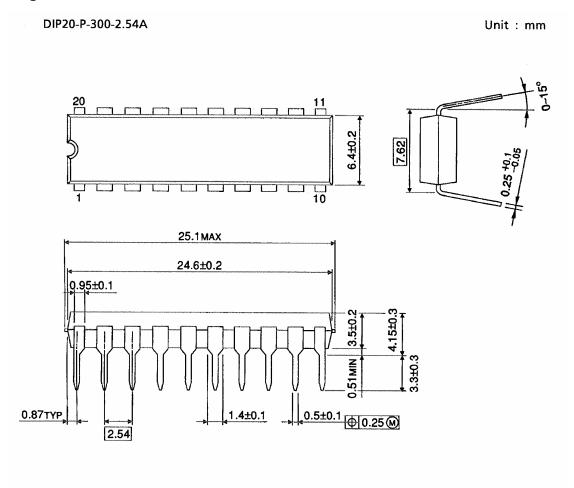
Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per F/F)

And the total C_{PD} when n pcs. of Flip Flop operate can be gained by the following equation.

$$C_{PD}$$
 (total) = 23 + 11 · n

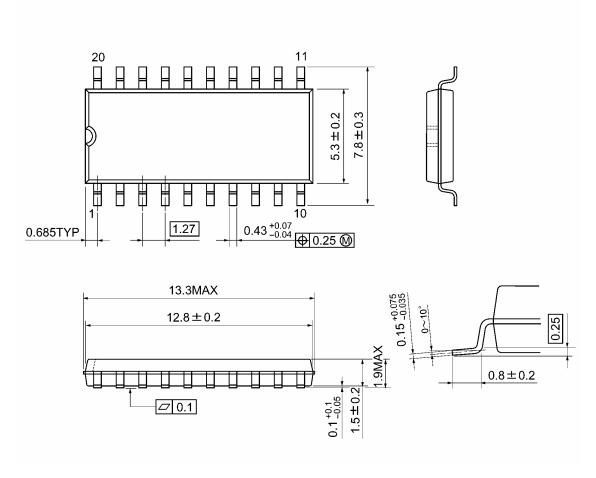
Package Dimensions



Weight: 1.30 g (typ.)

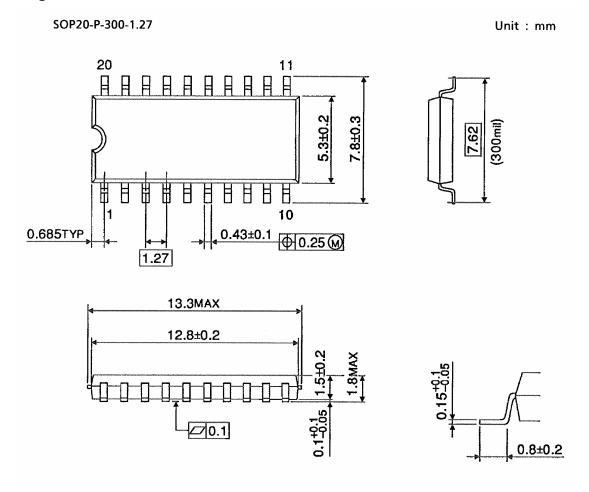
Package Dimensions

SOP20-P-300-1.27A Unit: mm



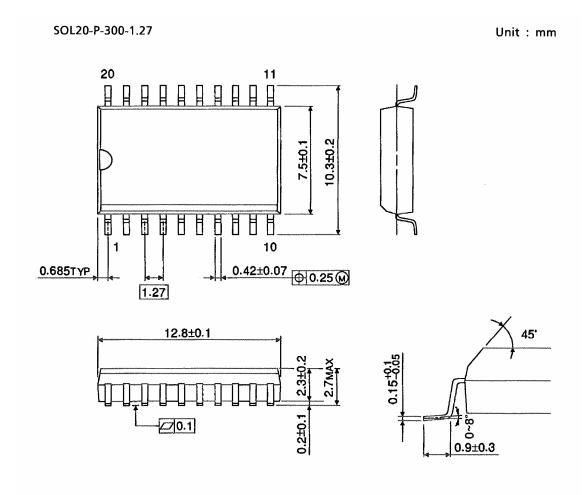
Weight: 0.22 g (typ.)

Package Dimensions



Weight: 0.22 g (typ.)

Package Dimensions (Note)



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Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

Note: Lead (Pb)-Free Packages

DIP20-P-300-2.54A SOP20-P-300-1.27A

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